NSN 5962-01-381-7361

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View Online at https://aerobasegroup.com/nsn/5962-01-381-7361

Body Length:

Between 0.640 inches and 0.660 inches

Body Height:

Between 0.080 inches and 0.100 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Wgu-2c/b guid e/i fscm 96214

Features Provided:

Programmable and tested to mil-std-883

Inclosure Material:

Ceramic

Inclosure Configuration:

Pin grid array

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

80.00 milliamperes forward current, nonrepetitive, peak total value minor

Terminal Surface Treatment:

Solder

Product Name:

32k x 8 eeprom

Voltage Rating And Type Per Characteristic:

-0.3 volts absolute input and 6.25 volts absolute input

Time Rating Per Chacteristic:

200.00 nanoseconds access and 10.00 milliseconds write-cycle width

Memory Device Type:

Eeprom

Hybrid Technology Type:

Monolithic

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

28 pin

Specification Data:

67268-5962-88525 government standard and 96214-2698759-2004 manufacturers specification control

Specification Or Standard:

04 type and u case and a finish

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	Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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